

electrode through a contact hole, a drain region that is connected to the data line through a second contact hole, a channel region disposed under the gate electrode, and a semiconductor portion protruding out of the channel region and not being covered with the gate electrode.

Please add new claim 24 as follows:

--24. (New) An electro-optical device, comprising:

a substrate;

a plurality of pixel electrodes;

a plurality of scanning lines;

a plurality of data lines, one of the data lines crossing one of the plurality of scanning line; and

a plurality of transistors disposed correspondingly to intersections between the plurality of data lines and the plurality of scanning lines, each of the plurality of transistors including a gate electrode and a semiconductor layer, wherein the semiconductor layer comprises a source region that is connected to one of the plurality of pixel electrodes through a contact hole, a drain region that is connected to the data line through a second contact hole, a channel region disposed under the gate electrode, and a semiconductor portion protruding out of the channel region and not being covered with the gate electrode.--

REMARKS

Claims 1-8, 20-21 and 24 are pending. By this Amendment, claim 1 is amended to clarify the claimed subject matter, and claim 24 is added. Support for these amendments is provided in the specification at least at page 9, lines 17-22, page 10, lines 8-20 and Figs. 1-3. No new matter has been added. Reconsideration in view of the above amendments and following remarks is respectfully requested. The attached Appendix includes marked-up copies of rewritten claim 1 (37 C.F.R. §1.121(c)(1)(ii)).

Entry of the amendments is proper under 37 CFR §1.116 since the amendments: (a) place the application in condition for allowance (for the reasons discussed herein); (b) do not